

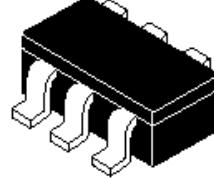
## High Gain, Low Noise Amplifier

PRELIMINARY DATA

- HIGH GAIN  $G_p = 21$  dB at 1.85 GHz
- LOW NOISE FIGURE  $NF = 1.3$  dB at 1.85 GHz
- LOW CURRENT CONSUMPTION 5.9 mA
- OPEN COLLECTOR OUTPUT
- TYPICAL SUPPLY VOLTAGE: 2.4-3 V
- GAIN-STEP-MODE (36dB)
- ULTRA MINIATURE SOT323-6L PACKAGE

### APPLICATIONS

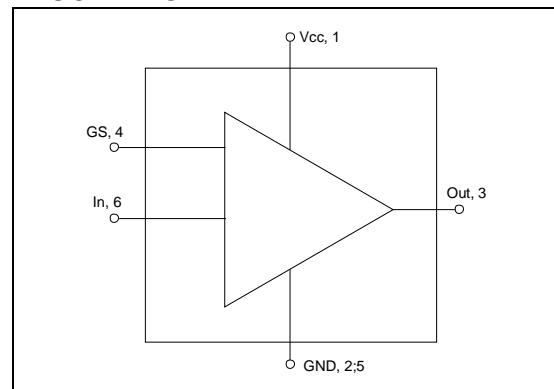
- LNA FOR CELLULAR MARKET (ideal for GSM900, DCS1800 and PCS1900).
- LNA FOR GPS APPLICATIONS



**SOT323-6L (SC70)**

ORDER CODE	BRANDING
TBD	TBD

### BLOCK DIAGRAM



### ABSOLUTE MAXIMUM RATINGS

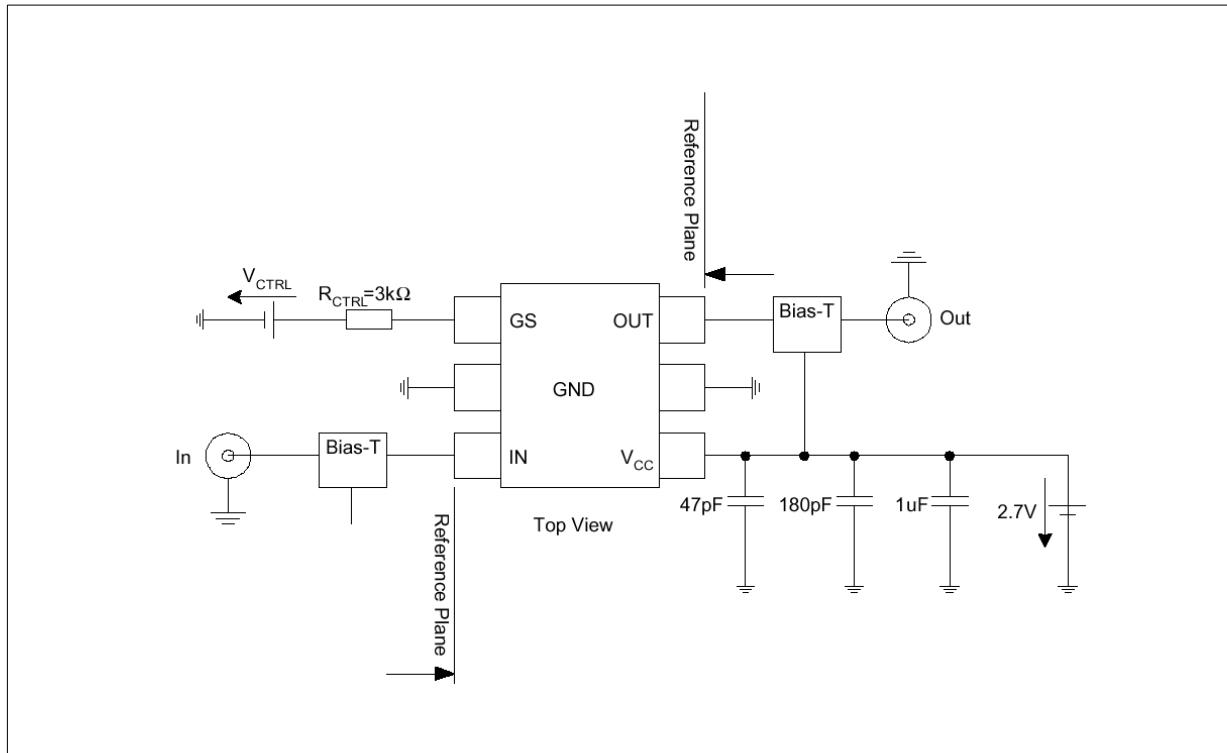
Symbol	Parameter	Value	Unit
$V_{cc}$	Device voltage	4.5	V
$V_{out}$	Voltage at pin Out	4.5	V
$V_{GS}$	Voltage at pin GS	3.5	V
$I_{tot}$	Total Device Current	12	mA
$I_{in}$	Current into pin In	0.5	mA
$P_{tot}$	Total dissipation, $T_s < 125$ °C	60	mW
$P_{IN}$	Input Power	8	dBm
$T_{op}$	Operating temperature	-40 to +85	°C
$T_{stg}$	Storage temperature	-65 to +150	°C
$T_j$	Max. operating junction temperature	150	°C

### THERMAL RESISTANCE

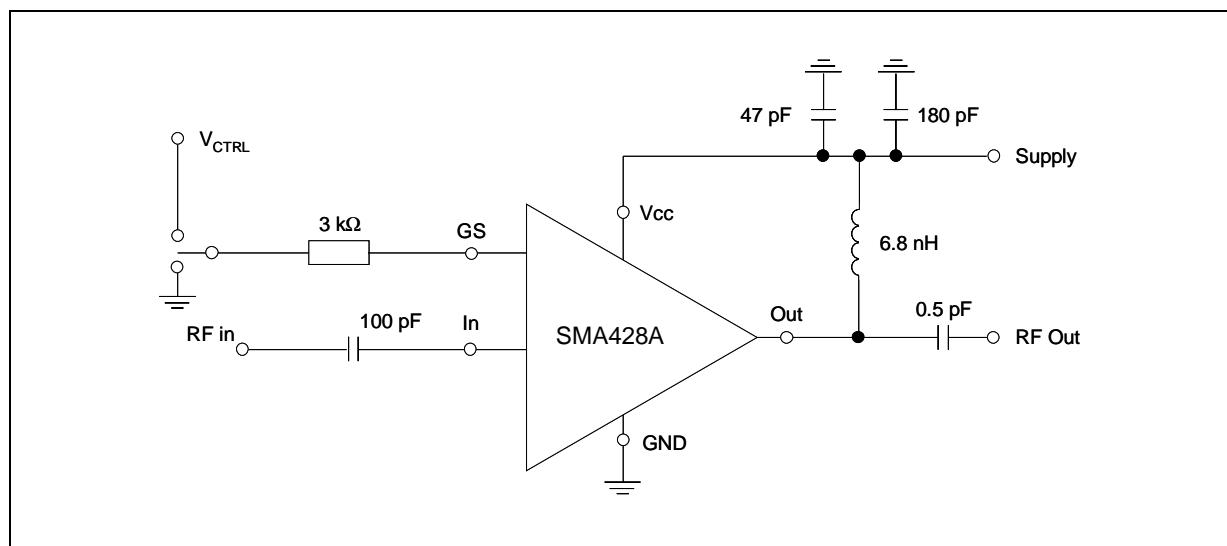
R <sub>thjs</sub>	Thermal Resistance Junction soldering point	TBD	°C/W
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## SMA428A

Test Circuit (Fig. 1)



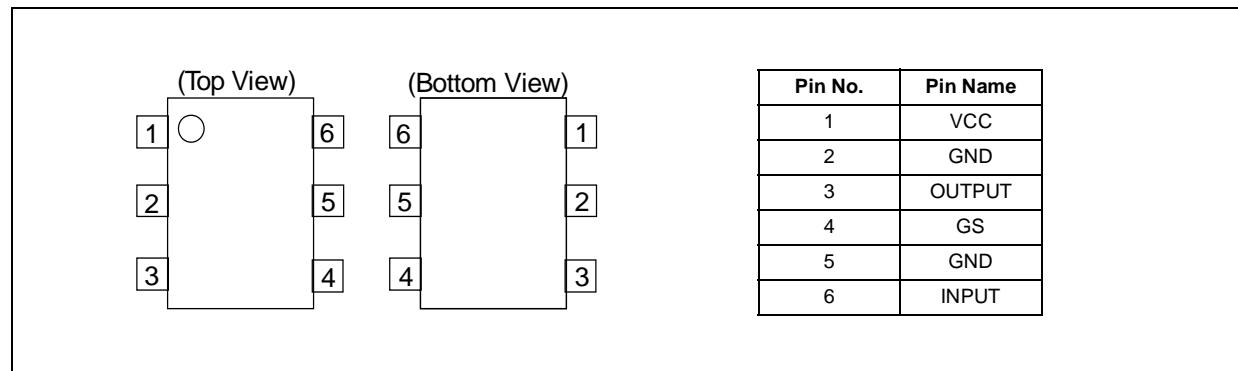
Typical application circuit (Fig. 2)



**ELECTRICAL CHARACTERISTICS**

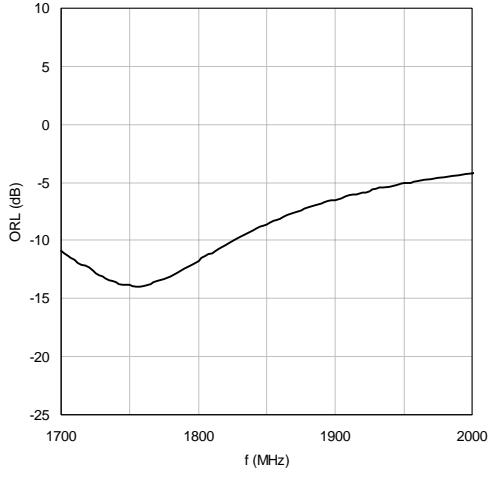
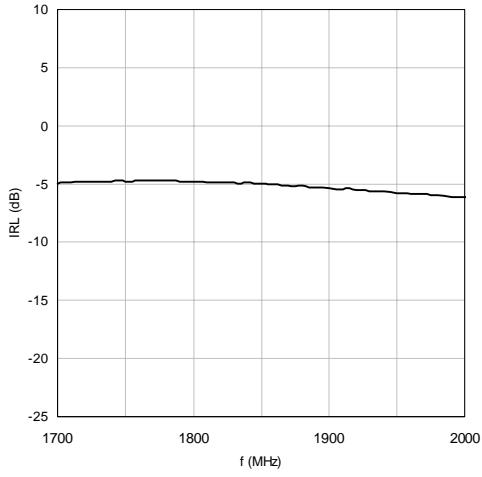
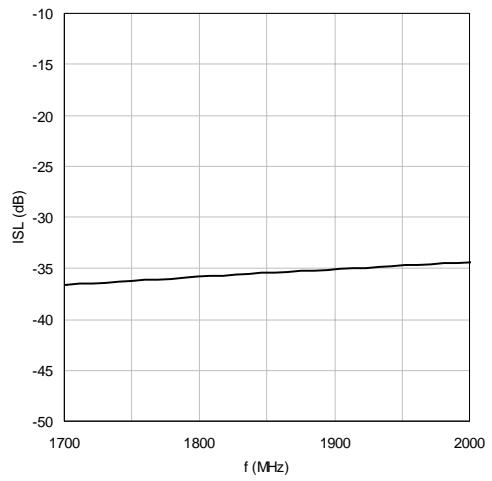
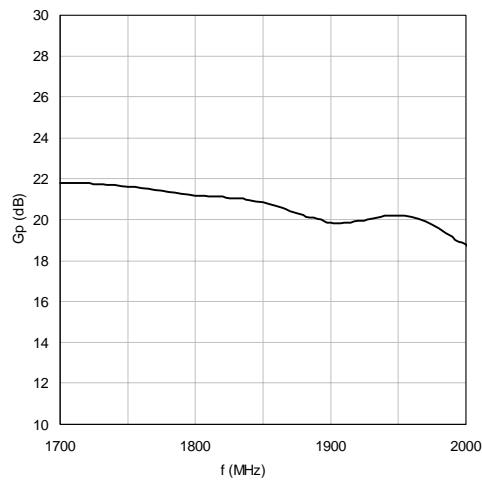
(Ta = +25°C, VCC = 2.7V, tested in circuit shown in fig.1, unless otherwise specified)

Symbol	Parameters	Test Conditions	Min	Typ	Max	Unit
f	Frequency Range			1850		MHz
Itot	Total device current			5.9		mA
Gp	Power Gain			21		dB
NF	Noise Figure (Zs = 50 Ω)			1.3		dB
P-1dB	Input Power at 1 dB Gain Compression			-19		dBm
IIP3	Input third order intercept point			-9.6		dBm
LGS	Insertion Loss in Gain-Step-Mode	Vcc = 0.0 V, VCTRL = 2.7 V, RCTRL = 3 kΩ		15		dB
ICTR	Current consumption in Gain-Step-Mode	Vcc = 0.0 V, VCTRL = 2.7 V, RCTRL = 3 kΩ		0.33		mA

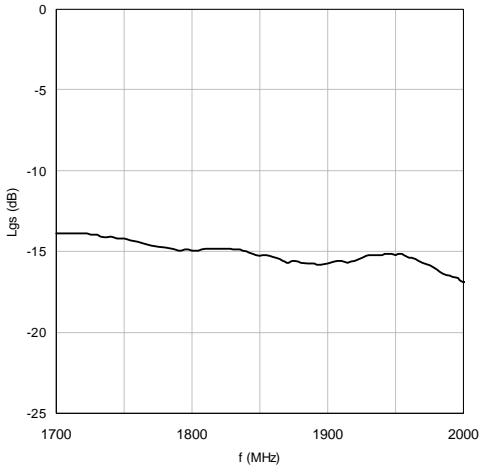
**PIN CONNECTION**

## SMA428A

**S-Parameters** ( $T_a = +25^{\circ}\text{C}$ ,  $Z_L = Z_S = 50 \Omega$ ,  $V_{CC} = 2.7\text{V}$ , measured in application circuit shown in fig.2)

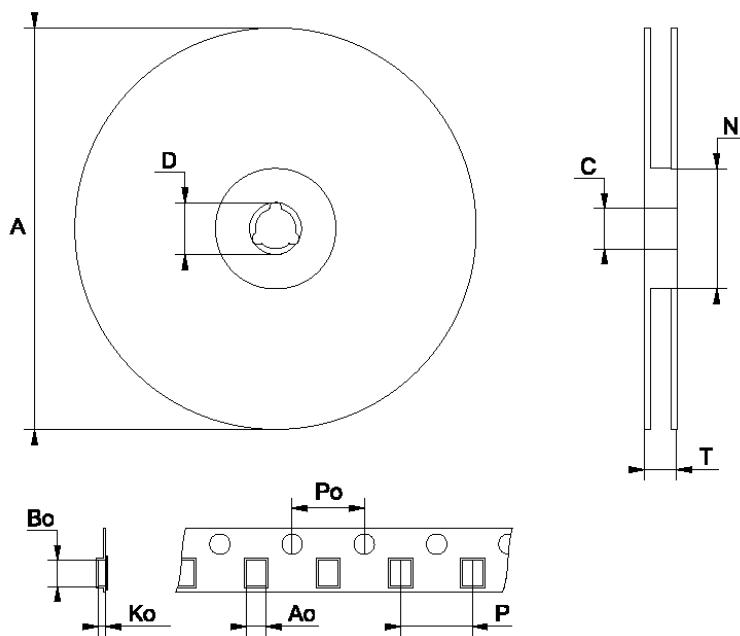


**Off-Gain** ( $V_{CC} = 0\text{V}$ ,  $V_{ctrl} = 2.7\text{V}$ ,  $R_{ctrl} = 3\text{Kohm}$ )

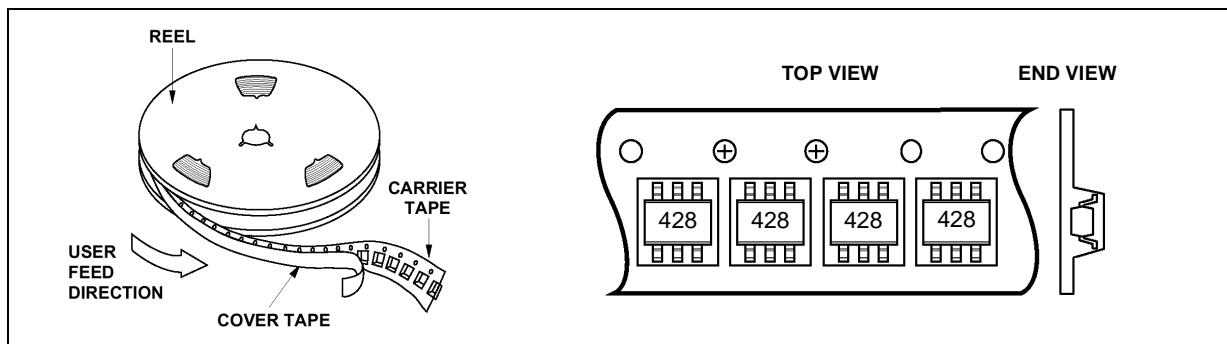


## TAPE &amp; REEL DIMENSIONS

	mm		
	MIN.	TYP.	MAX
A	178.5	179	179.5
C	12.8	13.0	13.5
D	20.2		
N	54.5	55	55.5
T			14.4
Ao		2.25	
Bo		2.7	
Ko		1.2	
Po	3.8 (cumulative 10 Po)	4.0	4.2 (cumulative 10 Po)
P		4.0	

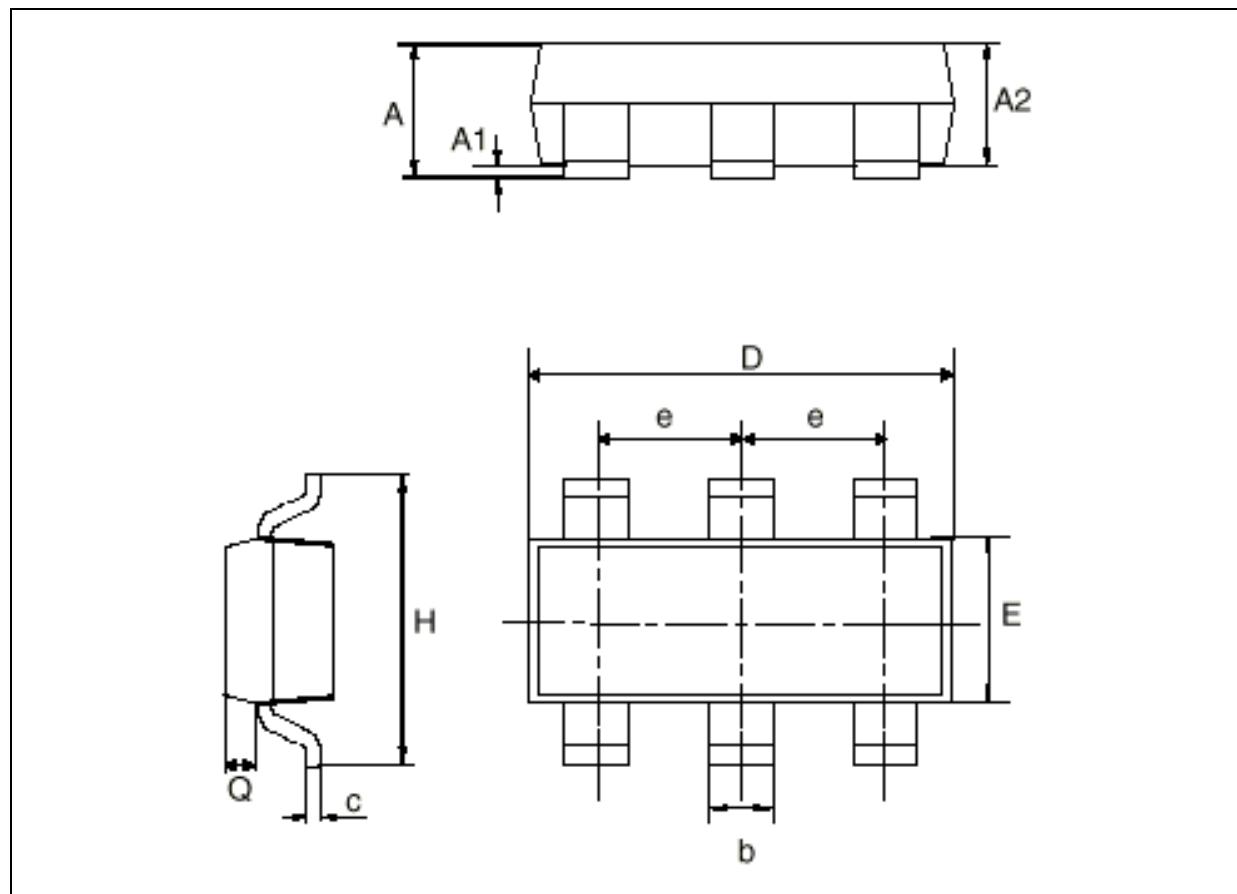


## DEVICE ORIENTATION



**SMA428A****SOT323-6L MECHANICAL DATA**

DIM.	mm			Inch		
	MIN.	TYP.	MAX	MIN.	TYP.	MAX
A	0.8		1.1	0.031		0.043
A1	0		0.1	0		0.004
A2	0.8		1	0.0031		0.039
b	0.15		0.3	0.006		0.012
c	0.1		0.18	0.004		0.007
D	1.8		2.2	0.071		0.088
E	1.15		1.35	0.045		0.59
e		0.65			0.025	
H	1.8		2.4	0.071		0.094
Q	0.1		0.4	0.004		0.016



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